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APPLICATION NO. FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/769,816	02/03/2004	Sang Yoon Lee	021269-009	9533		
21839	7590 09/24/2004	EXAMINER				
BURNS DOANE SWECKER & MATHIS L L P POST OFFICE BOX 1404 ALEXANDRIA, VA 22313-1404			NADAV, ORI			
			ART UNIT	PAPER NUMBER		
			2811	2811		
			DATE MAILED: 09/24/2004	DATE MAILED: 09/24/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	n No.	Applicant(s)	Alex			
Office Action Summary		10/769,81	6	LEE ET AL.				
		Examiner		Art Unit				
	·	ori nadav		2811				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status								
1)[⊠	Responsive to communication(s) filed on	03 February 200)4 .					
•		2b)⊠ This action is non-final.						
· /—								
Disposition of Claims								
4) ⊠ Claim(s) 1-11 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1-3 and 6-11 is/are rejected. 7) ⊠ Claim(s) 4 and 5 is/are objected to. 8) □ Claim(s) are subject to restriction and/or election requirement.								
Applicat	ion Papers							
9)[The specification is objected to by the Exa	miner.						
10)⊠ The drawing(s) filed on <u>03 February 2004</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.								
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority under 35 U.S.C. § 119								
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.								
Attachmer	nt(s)							
1) Notice 2) Notice 3) Information Paper	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-94 mation Disclosure Statement(s) (PTO-1449 or PTO/Ser No(s)/Mail Date 2/3/04.		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:	ate	D-152)			

Application/Control Number: 10/769,816

Art Unit: 2811

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-3 and 6-11 are rejected under 35 U.S.C. 103(a) as being unpatentable

over Kelly et al. (6,617,609) in view of Dimitrakopoulos et al. (5,981,970).

Kelly et al. teach (see column 2, line 65 to column 4, line 67) an organic thin film transistor, comprising a gate electrode, a gate insulating film, an organic active layer and a source/drain electrode, or a gate electrode, a gate insulating film, a source/drain electrode and an organic active layer, sequentially formed on a substrate,

wherein the gate insulating film is a multi-layered insulator comprising a first layer of a high k material and a second layer of an insulating organic polymer compatible with organic active layer (column 3, lines 64-67).

Kelly et al. do not state that the second layer is positioned directly under the organic active layer.

Dimitrakopoulos et al. teach in figure 6 a layer of gate insulating material positioned directly under the organic active layer.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to position the second layer directly under the organic active layer

Application/Control Number: 10/769,816

Art Unit: 2811

in Kelly et al.'s device in order to operate the device in a conventional method wherein the gate insulating layer is positioned directly under the active layer.

Regarding the process limitations recited in claims 1-2 and 7 ("sequentially formed on a substrate", "the first and the second layers of the gate insulating film are formed a wet process" and "the wet process is carried out by a spin coating, a dip coating, a printing, or a roll coating method"), these would not carry patentable weight in this claim drawn to a structure, because distinct structure is not necessarily produced.

Note that a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery, 186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); and In re Marosi et al., 218 USPQ 289, all of which make it clear that it is the patentability of the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. Note that the applicant has the burden of proof in such cases, as the above case law makes clear.

Regarding claims 3, 8-10, Kelly et al. teach a gate insulating material having a high k material of dielectric constant of 5 or higher. Dimitrakopoulos et al. teach the k high material for first insulating layer is mixture of an insulating organic polymer and an

Application/Control Number: 10/769,816

Art Unit: 2811

organic metal compound, or mixture of insulating organic polymer and nanoparticles inorganic metal oxide or a ferroelectric insulator. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use the high k material for first insulating layer as a mixture of an insulating organic polymer and an organic metal compound, or mixture of insulating organic polymer and nanoparticles inorganic metal oxide or a ferroelectric insulator, wherein the high k material has a dielectric constant of 5 or higher in Kelly et al.'s device in order to improve the dielectric properties of the device.

Regarding claims 6 and 11, Kelly et al. teach a substrate being plastic, glass, quartz, or silicon substrate, wherein the organic active layer is made of any one selected from the group consisting of pentacene, copper, phthalocyanine, polythiophene, polyaniline, polyacetylene, polypyrrole, polyphenylene vinylene, and derivatives thereof.

Allowable Subject Matter

Claims 4 and 5 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Reasons for allowance

The following is an examiner's statement of reasons for allowance: Kelly et al. (6,617,609) and Dimitrakopoulos et al. (5,981,970) appear to be the closest prior art reference. Kelly et al. and Dimitrakopoulos et al. teach substantially the entire claimed structure, as recited in claim 1, except the claimed material and formula for the insulating organic polymer. Therefore, prior art do not teach or render obviousness the semiconductor structure, as claimed.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Reference B is cited as being related to organic TFT..

Papers related to this application may be submitted to Technology center (TC)
2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC
2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such
papers must conform with the notice published in the Official Gazette, 1096 OG

Application/Control Number: 10/769,816 Page 6

Art Unit: 2811

30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used <u>only</u> for papers related to Group 2811 applications.

Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to *Examiner Nadav* whose telephone number is **(571) 272-1660**. The Examiner is in the Office generally between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center Receptionists** whose telephone number is **308-0956**

O.N. 9/22/04 ORI NADAV
PRIMARY EXAMINER
TECHNOLOGY CENTER 2800

Q. 16